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# Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

#### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	18432
Number of I/O	71
Number of Gates	60000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a3p060-1vqg100

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



ProASIC3 Devices	A3P015 <sup>1</sup>	A3P030	A3P060	A3P125	A3P250	A3P400	A3P600	A3P1000
Cortex-M1 Devices <sup>2</sup>					M1A3P250	M1A3P400	M1A3P600	M1A3P1000
Package Pins QFN	QN68	QN48, QN68, QN132 <sup>7</sup>	QN132 <sup>7</sup>	QN132 <sup>7</sup>	QN132 <sup>7</sup>			
CS VQFP TQFP PQFP		VQ100	CS121 VQ100 TQ144	VQ100 TQ144 PQ208	VQ100 PQ208	PQ208	PQ208	PQ208
FBGA			FG144	FG144	FG144/256 <sup>5</sup>	FG144/256/ 484	FG144/256/ 484	FG144/256/ 484

- A3P015 is not recommended for new designs.
   Refer to the Cortex-M1 product brief for more information.
   AES is not available for Cortex-M1 ProASIC3 devices.
   Six chip (main) and three quadrant global networks are available for A3P060 and above.
   The M1A3P250 device does not support this package.
   For higher densities and support of additional features, refer to the ProASIC3E Flash Family FPGAs datasheet.
   Package not available.

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# I/Os Per Package <sup>1</sup>

ProASIC3 Devices	A3P015 <sup>2</sup>	A3P030	A3P060	A3P125	A3P	250 <sup>3</sup>	A3P	400 <sup>3</sup>	A3F	P600	A3P	1000
Cortex-M1 Devices					M1A3F	250 <sup>3,5</sup>	M1A3	P400 <sup>3</sup>	M1A3	3P600	M1A3	P1000
					I/C	) Type						
Package	Single-Ended I/O	Single-Ended I/O	Single-Ended I/O	Single-Ended I/O	Single-Ended I/O <sup>4</sup>	Differential I/O Pairs						
QN48	_	34	_	_	-	_		_	_	_	_	_
QN68	49	49	_	_	_	_	_	_		_	_	_
QN132 <sup>7</sup>	_	81	80	84	87	19	_	-		_	_	_
CS121	_	_	96	_	-	_	_	_	_	_	_	_
VQ100	_	77	71	71	68	13	_	_		_	_	_
TQ144	_	_	91	100	-	_	_	_	_	_	_	_
PQ208	_	-	-	133	151	34	151	34	154	35	154	35
FG144	_	_	96	97	97	24	97	25	97	25	97	25
FG256 <sup>5,6</sup>	_	_	-	-	157	38	178	38	177	43	177	44
FG484 <sup>6</sup>	_	_	_	_	-	_	194	38	235	60	300	74

#### Notes

- 1. When considering migrating your design to a lower- or higher-density device, refer to the ProASIC3 FPGA Fabric User Guide to ensure complying with design and board migration requirements.
- 2. A3P015 is not recommended for new designs.
- 3. For A3P250 and A3P400 devices, the maximum number of LVPECL pairs in east and west banks cannot exceed 15. Refer to the ProASIC3 FPGA Fabric Users Guide for position assignments of the 15 LVPECL pairs.
- 4. Each used differential I/O pair reduces the number of single-ended I/Os available by two.
- 5. The M1A3P250 device does not support FG256 package.
- 6. FG256 and FG484 are footprint-compatible packages.
- 7. Package not available.

Table 1 • ProASIC3 FPGAs Package Sizes Dimensions

Package	CS121	QN48	QN68	QN132 *	VQ100	TQ144	PQ208	FG144	FG256	FG484
Length × Width (mm × mm)	6 × 6	6 × 6	8 × 8	8 × 8	14 × 14	20 × 20	28 × 28	13 × 13	17 × 17	23 × 23
Nominal Area (mm <sup>2</sup> )	36	36	64	64	196	400	784	169	289	529
Pitch (mm)	0.5	0.4	0.4	0.5	0.5	0.5	0.5	1.0	1.0	1.0
Height (mm)	0.99	0.90	0.90	0.75	1.00	1.40	3.40	1.45	1.60	2.23

Note: \* Package not available

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#### User Nonvolatile FlashROM

ProASIC3 devices have 1 kbit of on-chip, user-accessible, nonvolatile FlashROM. The FlashROM can be used in diverse system applications:

- · Internet protocol addressing (wireless or fixed)
- System calibration settings
- · Device serialization and/or inventory control
- Subscription-based business models (for example, set-top boxes)
- · Secure key storage for secure communications algorithms
- Asset management/tracking
- Date stamping
- · Version management

The FlashROM is written using the standard ProASIC3 IEEE 1532 JTAG programming interface. The core can be individually programmed (erased and written), and on-chip AES decryption can be used selectively to securely load data over public networks (except in the A3P015 and A3P030 devices), as in security keys stored in the FlashROM for a user design.

The FlashROM can be programmed via the JTAG programming interface, and its contents can be read back either through the JTAG programming interface or via direct FPGA core addressing. Note that the FlashROM can only be programmed from the JTAG interface and cannot be programmed from the internal logic array.

The FlashROM is programmed as 8 banks of 128 bits; however, reading is performed on a byte-by-byte basis using a synchronous interface. A 7-bit address from the FPGA core defines which of the 8 banks and which of the 16 bytes within that bank are being read. The three most significant bits (MSBs) of the FlashROM address determine the bank, and the four least significant bits (LSBs) of the FlashROM address define the byte.

The ProASIC3 development software solutions, Libero<sup>®</sup> System-on-Chip (SoC) and Designer, have extensive support for the FlashROM. One such feature is auto-generation of sequential programming files for applications requiring a unique serial number in each part. Another feature allows the inclusion of static data for system version control. Data for the FlashROM can be generated quickly and easily using Libero SoC and Designer software tools. Comprehensive programming file support is also included to allow for easy programming of large numbers of parts with differing FlashROM contents.

#### SRAM and FIFO

ProASIC3 devices (except the A3P015 and A3P030 devices) have embedded SRAM blocks along their north and south sides. Each variable-aspect-ratio SRAM block is 4,608 bits in size. Available memory configurations are 256×18, 512×9, 1k×4, 2k×2, and 4k×1 bits. The individual blocks have independent read and write ports that can be configured with different bit widths on each port. For example, data can be sent through a 4-bit port and read as a single bitstream. The embedded SRAM blocks can be initialized via the device JTAG port (ROM emulation mode) using the UJTAG macro (except in A3P015 and A3P030 devices).

In addition, every SRAM block has an embedded FIFO control unit. The control unit allows the SRAM block to be configured as a synchronous FIFO without using additional core VersaTiles. The FIFO width and depth are programmable. The FIFO also features programmable Almost Empty (AEMPTY) and Almost Full (AFULL) flags in addition to the normal Empty and Full flags. The embedded FIFO control unit contains the counters necessary for generation of the read and write address pointers. The embedded SRAM/FIFO blocks can be cascaded to create larger configurations.

#### PLL and CCC

ProASIC3 devices provide designers with very flexible clock conditioning capabilities. Each member of the ProASIC3 family contains six CCCs. One CCC (center west side) has a PLL. The A3P015 and A3P030 devices do not have a PLL.

The six CCC blocks are located at the four corners and the centers of the east and west sides.

All six CCC blocks are usable; the four corner CCCs and the east CCC allow simple clock delay operations as well as clock spine access.

The inputs of the six CCC blocks are accessible from the FPGA core or from one of several inputs located near the CCC that have dedicated connections to the CCC block.

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Table 2-32 • I/O Short Currents IOSH/IOSL
Applicable to Advanced I/O Banks

	Drive Strength	IOSL (mA) <sup>1</sup>	IOSH (mA) <sup>1</sup>
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	27	25
	4 mA	27	25
	6 mA	54	51
	8 mA	54	51
	12 mA	109	103
	16 mA	127	132
	24 mA	181	268
3.3 V LVCMOS Wide Range <sup>2</sup>	100 μΑ	Same as regular 3.3 V LVCMOS	Same as regular 3.3 V LVCMOS
2.5 V LVCMOS	2 mA	18	16
	4 mA	18	16
	6 mA	37	32
	8 mA	37	32
	12 mA	74	65
	16 mA	87	83
	24 mA	124	169
1.8 V LVCMOS	2 mA	11	9
	4 mA	22	17
	6 mA	44	35
	8 mA	51	45
	12 mA	74	91
	16 mA	74	91
1.5 V LVCMOS	2 mA	16	13
	4 mA	33	25
	6 mA	39	32
	8 mA	55	66
	12 mA	55	66
3.3 V PCI/PCI-X	Per PCI/PCI-X specification	109	103

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<sup>1.</sup>  $T_J = 100^{\circ}C$ 

<sup>2.</sup> Applicable to 3.3 V LVCMOS Wide Range. I<sub>OSL</sub>/I<sub>OSH</sub> dependent on the I/O buffer drive strength selected for wide range applications. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.



Table 2-44 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Standard Plus I/O Banks

	, .bb	DIE 10 OI											
Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	9.68	0.04	1.00	0.43	9.86	8.42	2.28	2.21	12.09	10.66	ns
	-1	0.56	8.23	0.04	0.85	0.36	8.39	7.17	1.94	1.88	10.29	9.07	ns
	-2	0.49	7.23	0.03	0.75	0.32	7.36	6.29	1.70	1.65	9.03	7.96	ns
4 mA	Std.	0.66	9.68	0.04	1.00	0.43	9.86	8.42	2.28	2.21	12.09	10.66	ns
	-1	0.56	8.23	0.04	0.85	0.36	8.39	7.17	1.94	1.88	10.29	9.07	ns
	-2	0.49	7.23	0.03	0.75	0.32	7.36	6.29	1.70	1.65	9.03	7.96	ns
6 mA	Std.	0.66	6.70	0.04	1.00	0.43	6.82	5.89	2.58	2.74	9.06	8.12	ns
	-1	0.56	5.70	0.04	0.85	0.36	5.80	5.01	2.20	2.33	7.71	6.91	ns
	-2	0.49	5.00	0.03	0.75	0.32	5.10	4.40	1.93	2.05	6.76	6.06	ns
8 mA	Std.	0.66	6.70	0.04	1.00	0.43	6.82	5.89	2.58	2.74	9.06	8.12	ns
	-1	0.56	5.70	0.04	0.85	0.36	5.80	5.01	2.20	2.33	7.71	6.91	ns
	-2	0.49	5.00	0.03	0.75	0.32	5.10	4.40	1.93	2.05	6.76	6.06	ns
12 mA	Std.	0.66	5.05	0.04	1.00	0.43	5.14	4.51	2.79	3.08	7.38	6.75	ns
	-1	0.56	4.29	0.04	0.85	0.36	4.37	3.84	2.38	2.62	6.28	5.74	ns
	-2	0.49	3.77	0.03	0.75	0.32	3.84	3.37	2.09	2.30	5.51	5.04	ns
16 mA	Std.	0.66	5.05	0.04	1.00	0.43	5.14	4.51	2.79	3.08	7.38	6.75	ns
	-1	0.56	4.29	0.04	0.85	0.36	4.37	3.84	2.38	2.62	6.28	5.74	ns
	-2	0.49	3.77	0.03	0.75	0.32	3.84	3.37	2.09	2.30	5.51	5.04	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-45 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V
Applicable to Standard I/O Banks

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	7.07	0.04	1.00	0.43	7.20	6.23	2.07	2.15	ns
	<b>–</b> 1	0.56	6.01	0.04	0.85	0.36	6.12	5.30	1.76	1.83	ns
	-2	0.49	5.28	0.03	0.75	0.32	5.37	4.65	1.55	1.60	ns
4 mA	Std.	0.66	7.07	0.04	1.00	0.43	7.20	6.23	2.07	2.15	ns
	-1	0.56	6.01	0.04	0.85	0.36	6.12	5.30	1.76	1.83	ns
	-2	0.49	5.28	0.03	0.75	0.32	5.37	4.65	1.55	1.60	ns
6 mA	Std.	0.66	4.41	0.04	1.00	0.43	4.49	3.75	2.39	2.69	ns
	-1	0.56	3.75	0.04	0.85	0.36	3.82	3.19	2.04	2.29	ns
	-2	0.49	3.29	0.03	0.75	0.32	3.36	2.80	1.79	2.01	ns
8 mA	Std.	0.66	4.41	0.04	1.00	0.43	4.49	3.75	2.39	2.69	ns
	-1	0.56	3.75	0.04	0.85	0.36	3.82	3.19	2.04	2.29	ns

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#### 3.3 V LVCMOS Wide Range

Table 2-47 • Minimum and Maximum DC Input and Output Levels
Applicable to Advanced I/O Banks

3.3 V LVCMOS Wide Range	Equiv. Software Default	٧	IL	V	IH	VOL	VOH	IOL	ЮН	IOSL	юѕн	IIL <sup>2</sup>	IIH <sup>3</sup>
Drive Strength	Drive Strength Option <sup>1</sup>	Min V	Max V	Min V	Max V	Max V	Min V	μΑ	μΑ	Max mA <sup>4</sup>	Max mA <sup>4</sup>	μΑ <sup>5</sup>	μ <b>Α</b> <sup>5</sup>
100 μΑ	2 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	25	27	10	10
100 μΑ	4 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	25	27	10	10
100 μΑ	6 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	51	54	10	10
100 μΑ	8 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	51	54	10	10
100 μΑ	12 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	103	109	10	10
100 μΑ	16 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	132	127	10	10
100 μΑ	24 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	268	181	10	10

#### Notes:

- 1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 3. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges
- 4. Currents are measured at 85°C junction temperature.
- 5. All LVMCOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
- 6. Software default selection highlighted in gray.

Table 2-48 • Minimum and Maximum DC Input and Output Levels
Applicable to Standard Plus I/O Banks

3.3 V LVCMOS Wide Range	Equiv. Software	VI	L	٧	IH	VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>2</sup>	IIH <sup>3</sup>
Drive Strength	Default Drive Strength Option <sup>1</sup>	Min V	Max V	Min V	Max V	Max V	Min V	μΑ	μА	Max mA <sup>4</sup>	Max mA <sup>4</sup>	μ <b>Α</b> <sup>5</sup>	μ <b>Α</b> <sup>5</sup>
100 µA	2 mA	-0.3	0.8	2	3.6	0.2	VDD – 0.2	100	100	25	27	10	10
100 μΑ	4 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	25	27	10	10
100 µA	6 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	51	54	10	10
100 μΑ	8 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	51	54	10	10
100 μΑ	12 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	103	109	10	10
100 μΑ	16 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	103	109	10	10

#### Notes:

- 1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 3. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges
- 4. Currents are measured at 85°C junction temperature.
- 5. All LVMCOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.
- 6. Software default selection highlighted in gray.

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Table 2-52 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V
Applicable to Standard Plus I/O Banks

Drive Strength	Equiv. Software Default Drive Strength Option <sup>1</sup>	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zнs</sub>	Units
100 μΑ	2 mA	Std.	0.60	11.14	0.04	1.52	0.43	11.14	9.54	3.51	3.61	14.53	12.94	ns
		<b>–1</b>	0.51	9.48	0.04	1.29	0.36	9.48	8.12	2.99	3.07	12.36	11.00	ns
		-2	0.45	8.32	0.03	1.14	0.32	8.32	7.13	2.62	2.70	10.85	9.66	ns
100 μΑ	4 mA	Std.	0.60	6.96	0.04	1.52	0.43	6.96	5.79	3.99	4.45	10.35	9.19	ns
		<b>–1</b>	0.51	5.92	0.04	1.29	0.36	5.92	4.93	3.39	3.78	8.81	7.82	ns
		-2	0.45	5.20	0.03	1.14	0.32	5.20	4.33	2.98	3.32	7.73	6.86	ns
100 μΑ	6 mA	Std.	0.60	6.96	0.04	1.52	0.43	6.96	5.79	3.99	4.45	10.35	9.19	ns
		-1	0.51	5.92	0.04	1.29	0.36	5.92	4.93	3.39	3.78	8.81	7.82	ns
		-2	0.45	5.20	0.03	1.14	0.32	5.20	4.33	2.98	3.32	7.73	6.86	ns
100 μΑ	8 mA	Std.	0.60	4.89	0.04	1.52	0.43	4.89	3.92	4.31	4.98	8.28	7.32	ns
		-1	0.51	4.16	0.04	1.29	0.36	4.16	3.34	3.67	4.24	7.04	6.22	ns
		-2	0.45	3.65	0.03	1.14	0.32	3.65	2.93	3.22	3.72	6.18	5.46	ns
100 μΑ	16 mA	Std.	0.60	4.89	0.04	1.52	0.43	4.89	3.92	4.31	4.98	8.28	7.32	ns
		-1	0.51	4.16	0.04	1.29	0.36	4.16	3.34	3.67	4.24	7.04	6.22	ns
		-2	0.45	3.65	0.03	1.14	0.32	3.65	2.93	3.22	3.72	6.18	5.46	ns

- 1. The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is  $\pm 100~\mu$ A. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
- 2. Software default selection highlighted in gray.
- 3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

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Table 2-53 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Standard Plus I/O Banks

	Equiv. Software													
Drive Strength	Default Drive Strength Option <sup>1</sup>	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
100 μΑ	2 mA	Std.	0.60	14.97	0.04	1.52	0.43	14.97	12.79	3.52	3.41	18.36	16.18	ns
		<b>–1</b>	0.51	12.73	0.04	1.29	0.36	12.73	10.88	2.99	2.90	15.62	13.77	ns
		-2	0.45	11.18	0.03	1.14	0.32	11.18	9.55	2.63	2.55	13.71	12.08	ns
100 μΑ	4 mA	Std.	0.60	10.36	0.04	1.52	0.43	10.36	8.93	3.99	4.24	13.75	12.33	ns
		<b>–1</b>	0.51	8.81	0.04	1.29	0.36	8.81	7.60	3.39	3.60	11.70	10.49	ns
		-2	0.45	7.74	0.03	1.14	0.32	7.74	6.67	2.98	3.16	10.27	9.21	ns
100 μΑ	6 mA	Std.	0.60	10.36	0.04	1.52	0.43	10.36	8.93	3.99	4.24	13.75	12.33	ns
		-1	0.51	8.81	0.04	1.29	0.36	8.81	7.60	3.39	3.60	11.70	10.49	ns
		-2	0.45	7.74	0.03	1.14	0.32	7.74	6.67	2.98	3.16	10.27	9.21	ns
100 μΑ	8 mA	Std.	0.60	7.81	0.04	1.52	0.43	7.81	6.85	4.32	4.76	11.20	10.24	ns
		<b>–1</b>	0.51	6.64	0.04	1.29	0.36	6.64	5.82	3.67	4.05	9.53	8.71	ns
		-2	0.45	5.83	0.03	1.14	0.32	5.83	5.11	3.22	3.56	8.36	7.65	ns
100 μΑ	16 mA	Std.	0.60	7.81	0.04	1.52	0.43	7.81	6.85	4.32	4.76	11.20	10.24	ns
		<b>–1</b>	0.51	6.64	0.04	1.29	0.36	6.64	5.82	3.67	4.05	9.53	8.71	ns
		-2	0.45	5.83	0.03	1.14	0.32	5.83	5.11	3.22	3.56	8.36	7.65	ns

<sup>1.</sup> The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 μA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.

<sup>2.</sup> For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



Table 2-64 • 2.5 V LVCMOS High Slew
Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V
Applicable to Standard I/O Banks

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	8.20	0.04	1.29	0.43	7.24	8.20	2.03	1.91	ns
	<b>–</b> 1	0.56	6.98	0.04	1.10	0.36	6.16	6.98	1.73	1.62	ns
	-2	0.49	6.13	0.03	0.96	0.32	5.41	6.13	1.52	1.43	ns
4 mA	Std.	0.66	8.20	0.04	1.29	0.43	7.24	8.20	2.03	1.91	ns
	-1	0.56	6.98	0.04	1.10	0.36	6.16	6.98	1.73	1.62	ns
	-2	0.49	6.13	0.03	0.96	0.32	5.41	6.13	1.52	1.43	ns
6 mA	Std.	0.66	4.77	0.04	1.29	0.43	4.55	4.77	2.38	2.55	ns
	-1	0.56	4.05	0.04	1.10	0.36	3.87	4.05	2.03	2.17	ns
	-2	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns
8 mA	Std.	0.66	4.77	0.04	1.29	0.43	4.55	4.77	2.38	2.55	ns
	-1	0.56	4.05	0.04	1.10	0.36	3.87	4.05	2.03	2.17	ns
	-2	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns

- 1. Software default selection highlighted in gray.
- 2. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-65 • 2.5 V LVCMOS Low Slew

Commercial-Case Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

Applicable to Standard I/O Banks

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	11.00	0.04	1.29	0.43	10.37	11.00	2.03	1.83	ns
	<b>–</b> 1	0.56	9.35	0.04	1.10	0.36	8.83	9.35	1.73	1.56	ns
	-2	0.49	8.21	0.03	0.96	0.32	7.75	8.21	1.52	1.37	ns
4 mA	Std.	0.66	11.00	0.04	1.29	0.43	10.37	11.00	2.03	1.83	ns
	<b>–</b> 1	0.56	9.35	0.04	1.10	0.36	8.83	9.35	1.73	1.56	ns
	-2	0.49	8.21	0.03	0.96	0.32	7.75	8.21	1.52	1.37	ns
6 mA	Std.	0.66	7.50	0.04	1.29	0.43	7.36	7.50	2.39	2.46	ns
	<b>–</b> 1	0.56	6.38	0.04	1.10	0.36	6.26	6.38	2.03	2.10	ns
	-2	0.49	5.60	0.03	0.96	0.32	5.49	5.60	1.78	1.84	ns
8 mA	Std.	0.66	7.50	0.04	1.29	0.43	7.36	7.50	2.39	2.46	ns
	-1	0.56	6.38	0.04	1.10	0.36	6.26	6.38	2.03	2.10	ns
	-2	0.49	5.60	0.03	0.96	0.32	5.49	5.60	1.78	1.84	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



Table 2-93 • Minimum and Maximum DC Input and Output Levels

DC Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Units
VCCI	Supply Voltage	3.	0	3	.3	3	.6	V
VOL	Output Low Voltage	0.96	1.27	1.06	1.43	1.30	1.57	V
VOH	Output High Voltage	1.8	2.11	1.92	2.28	2.13	2.41	V
VIL, VIH	Input Low, Input High Voltages	0	3.6	0	3.6	0	3.6	V
VODIFF	Differential Output Voltage	0.625	0.97	0.625	0.97	0.625	0.97	V
VOCM	Output Common-Mode Voltage	1.762	1.98	1.762	1.98	1.762	1.98	V
VICM	Input Common-Mode Voltage	1.01	2.57	1.01	2.57	1.01	2.57	V
VIDIFF	Input Differential Voltage	300		300		300		mV

#### Table 2-94 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)
1.64	1.94	Cross point

Note: \*Measuring point =  $V_{trip.}$  See Table 2-22 on page 2-22 for a complete table of trip points.

#### **Timing Characteristics**

Table 2-95 • LVPECL

Commercial-Case Conditions:  $T_J = 70$ °C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	0.66	1.80	0.04	1.40	ns
<b>-1</b>	0.56	1.53	0.04	1.19	ns
-2	0.49	1.34	0.03	1.05	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## **Clock Conditioning Circuits**

### **CCC Electrical Specifications**

#### **Timing Characteristics**

#### Table 2-115 • ProASIC3 CCC/PLL Specification

Parameter	Minimum	Typical	Maximum	Units
Clock Conditioning Circuitry Input Frequency f <sub>IN CCC</sub>	1.5		350	MHz
Clock Conditioning Circuitry Output Frequency f <sub>OUT CCC</sub>	0.75		350	MHz
Serial Clock (SCLK) for Dynamic PLL <sup>1</sup>			125	MHz
Delay Increments in Programmable Delay Blocks <sup>2, 3</sup>		200 <sup>4</sup>		ps
Number of Programmable Values in Each Programmabl Delay Block	е		32	
Input Period Jitter			1.5	ns
CCC Output Peak-to-Peak Period Jitter F <sub>CCC_OUT</sub>	IV	lax Peak-to-l	Peak Period Jitte	er
	1 Global Network Used		3 Global Networks Used	
0.75 MHz to 24 MHz	0.50%		0.70%	
24 MHz to 100 MHz	1.00%		1.20%	
100 MHz to 250 MHz	1.75%		2.00%	
250 MHz to 350 MHz	2.50%		5.60%	
Acquisition Time				
(A3P250 and A3P1000 only) LockControl = 0			300	μs
LockControl = 1			300	μs
(all other dies) LockControl = 0			300	μs
LockControl = 1			6.0	ms
Tracking Jitter <sup>5</sup>				
(A3P250 and A3P1000 only) LockControl = 0			1.6	ns
LockControl = 1			1.6	ns
(all other dies) LockControl = 0			1.6	ns
LockControl = 1			0.8	ns
Output Duty Cycle	48.5		51.5	%
Delay Range in Block: Programmable Delay 1 <sup>2, 3</sup>	0.6		5.56	ns
Delay Range in Block: Programmable Delay 2 <sup>2, 3</sup>	0.225		5.56	ns
Delay Range in Block: Fixed Delay <sup>2, 3</sup>		2.2		ns

#### Notes:

- 1. Maximum value obtained for a -2 speed-grade device in worst-case commercial conditions. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.
- 2. This delay is a function of voltage and temperature. See Table 2-6 on page 2-6 for deratings.
- 3.  $T_J = 25^{\circ}C$ , VCC = 1.5 V
- 4. When the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available. Refer to the Libero SoC Online Help for more information.
- Tracking jitter is defined as the variation in clock edge position of PLL outputs with reference to the PLL input clock edge. Tracking jitter does not measure the variation in PLL output period, which is covered by the period jitter parameter.
- 6. The A3P030 device does not contain a PLL.



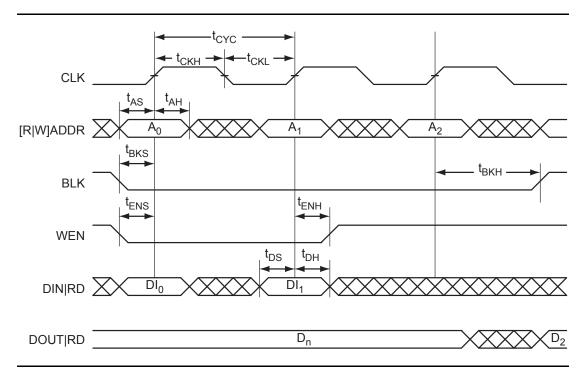


Figure 2-33 • RAM Write, Output Retained. Applicable to Both RAM4K9 and RAM512x18.

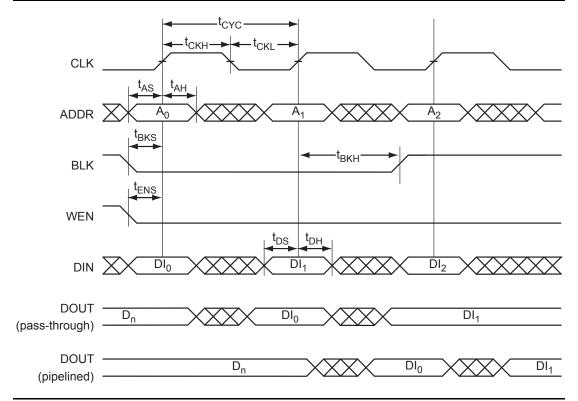


Figure 2-34 • RAM Write, Output as Write Data (WMODE = 1). Applicable to RAM4K9 Only.



#### **FIFO**

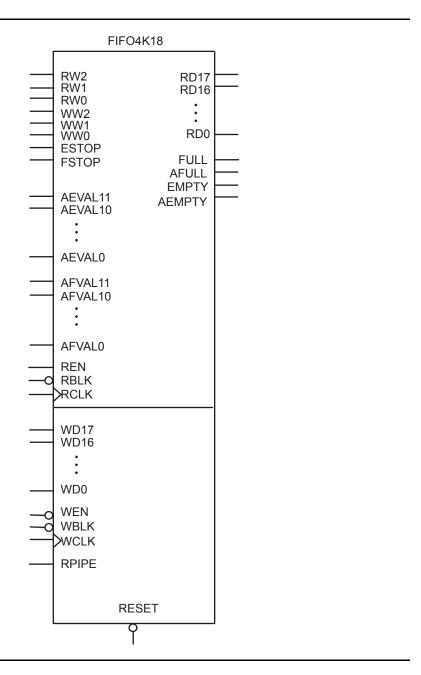


Figure 2-36 • FIFO Model



## Package Pin Assignments

01140					
QN48					
Pin Number	A3P030 Function				
1	IO82RSB1				
2	GEC0/IO73RSB1				
3	GEA0/IO72RSB1				
4	GEB0/IO71RSB1				
5	GND				
6	VCCIB1				
7	IO68RSB1				
8	IO67RSB1				
9	IO66RSB1				
10	IO65RSB1				
11	IO64RSB1				
12	IO62RSB1				
13	IO61RSB1				
14	IO60RSB1				
15	IO57RSB1				
16	IO55RSB1				
17	IO53RSB1				
18	VCC				
19	VCCIB1				
20	IO46RSB1				
21	IO42RSB1				
22	TCK				
23	TDI				
24	TMS				
25	VPUMP				
26	TDO				
27	TRST				
28	VJTAG				
29	IO38RSB0				
30	GDB0/IO34RSB0				
31	GDA0/IO33RSB0				
32	GDC0/IO32RSB0				
33	VCCIB0				
34	GND				
35	VCC				
36	IO25RSB0				

QN48					
Pin Number	A3P030 Function				
37	IO24RSB0				
38	IO22RSB0				
39	IO20RSB0				
40	IO18RSB0				
41	IO16RSB0				
42	IO14RSB0				
43	IO10RSB0				
44	IO08RSB0				
45	IO06RSB0				
46	IO04RSB0				
47	IO02RSB0				
48	IO00RSB0				

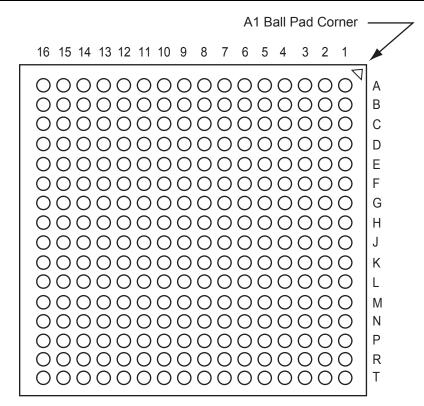
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FG144					
Pin Number	A3P125 Function				
K1	GEB0/IO109RSB1				
K2	GEA1/IO108RSB1				
K3	GEA0/IO107RSB1				
K4	GEA2/IO106RSB1				
K5	IO100RSB1				
K6	IO98RSB1				
K7	GND				
K8	IO73RSB1				
K9	GDC2/IO72RSB1				
K10	GND				
K11	GDA0/IO66RSB0				
K12	GDB0/IO64RSB0				
L1	GND				
L2	VMV1				
L3	GEB2/IO105RSB1				
L4	IO102RSB1				
L5	VCCIB1				
L6	IO95RSB1				
L7	IO85RSB1				
L8	IO74RSB1				
L9	TMS				
L10	VJTAG				
L11	VMV1				
L12	TRST				
M1	GNDQ				
M2	GEC2/IO104RSB1				
M3	IO103RSB1				
M4	IO101RSB1				
M5	IO97RSB1				
M6	IO94RSB1				
M7	IO86RSB1				
M8	IO75RSB1				
M9	TDI				
M10	VCCIB1				
M11	VPUMP				
M12	GNDQ				
2	55 %				



### FG256 - Bottom View



#### Note

For more information on package drawings, see PD3068: Package Mechanical Drawings.

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FG256				
Pin Number	A3P1000 Function			
H3	GFB1/IO208PPB3			
H4	VCOMPLF			
H5	GFC0/IO209NPB3			
H6	VCC			
H7	GND			
H8	GND			
H9	GND			
H10	GND			
H11	VCC			
H12	GCC0/IO91NPB1			
H13	GCB1/IO92PPB1			
H14	GCA0/IO93NPB1			
H15	IO96NPB1			
H16	GCB0/IO92NPB1			
J1	GFA2/IO206PSB3			
J2	GFA1/IO207PDB3			
J3	VCCPLF			
J4	IO205NDB3			
J5	GFB2/IO205PDB3			
J6	VCC			
J7	GND			
J8	GND			
J9	GND			
J10	GND			
J11	VCC			
J12	GCB2/IO95PPB1			
J13	GCA1/IO93PPB1			
J14	GCC2/IO96PPB1			
J15	IO100PPB1			
J16	GCA2/IO94PSB1			
K1	GFC2/IO204PDB3			
K2	IO204NDB3			
K3	IO203NDB3			
K4	IO203PDB3			
K5	VCCIB3			
K6	VCC			
K7	GND			
K8	GND			

FG256				
Pin Number	A3P1000 Function			
K9	GND			
K10	GND			
K11	VCC			
K12	VCCIB1			
K12	IO95NPB1			
K14	IO100NPB1			
K15	IO102NDB1			
K16	IO102PDB1			
L1	IO202NDB3			
L2	IO202PDB3			
L2 L3				
	IO196PPB3			
L4	IO193PPB3			
L5	VCCIB3			
L6	GND			
L7	VCC			
L8	VCC			
L9	VCC			
L10	VCC			
L11	GND			
L12	VCCIB1			
L13	GDB0/IO112NPB1			
L14	IO106NDB1			
L15	IO106PDB1			
L16	IO107PDB1			
M1	IO197NSB3			
M2	IO196NPB3			
M3	IO193NPB3			
M4	GEC0/IO190NPB3			
M5	VMV3			
M6	VCCIB2			
M7	VCCIB2			
M8	IO147RSB2			
M9	IO136RSB2			
M10	VCCIB2			
M11	VCCIB2			
M12	VMV2			
M13	IO110NDB1			
M14	GDB1/IO112PPB1			

FG256				
Pin Number	A3P1000 Function			
M15	GDC1/IO111PDB1			
M16	IO107NDB1			
N1	IO194PSB3			
N2	IO192PPB3			
N3	GEC1/IO190PPB3			
N4	IO192NPB3			
N5	GNDQ			
N6	GEA2/IO187RSB2			
N7	IO161RSB2			
N8	IO155RSB2			
N9	IO141RSB2			
N10	IO141RSB2			
N10	IO129RSB2			
N12	GNDQ IO110PDP1			
N13	IO110PDB1			
N14	VJTAG			
N15	GDC0/IO111NDB1			
N16	GDA1/IO113PDB1			
P1	GEB1/IO189PDB3			
P2	GEB0/IO189NDB3			
P3	VMV2			
P4	IO179RSB2			
P5	IO171RSB2			
P6	IO165RSB2			
P7	IO159RSB2			
P8	IO151RSB2			
P9	IO137RSB2			
P10	IO134RSB2			
P11	IO128RSB2			
P12	VMV1			
P13	TCK			
P14	VPUMP			
P15	TRST			
P16	GDA0/IO113NDB1			
R1	GEA1/IO188PDB3			
R2	GEA0/IO188NDB3			
R3	IO184RSB2			
R4	GEC2/IO185RSB2			



# 5 - Datasheet Information

## **List of Changes**

The following table lists critical changes that were made in each version of the ProASIC3 datasheet.

Revision	Changes	Page
Revision 18 (March 2016)	Updated 3.3 V DC supply voltage's maximum Commercial and Industrial values from 3.3 V to 3.6 V in Table 2-2 (SAR 72693).	2-2
	Added reference of Package Mechanical Drawings document in all package pin assignment notes (76833).	NA
Revision 17	Removed PQFP embedded heat spreader info. from Table 2-5 (SAR 52320).	2-6
(June 2015)	Updated "VCCIBx I/O Supply Voltage" (SAR 43323).	3-1
Revision 16 (December 2014)	Updated "ProASIC3 Ordering Information". Interchanged the positions of Y- Security Feature and I- Application (Temperature Range) (SAR 61079). Added Note "Only devices with package size greater than or equal to 5x5 are supported".	1-IV
	Updated Table Note (2) in Table 2-3 • Flash Programming Limits – Retention, Storage and Operating Temperature so that the Table Note is not applicable for Maximum Storage Temperature T <sub>STG</sub> (SAR 54297).	2-3
	Added values for Drive strength 2 mA in Table 2-41 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew, Table 2-42 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew, Table 2-43 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew, and Table 2-44 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew (SAR 57184).	2-34, 2-35, 2-36, 2-37
	Added Figure 2-1 • High-Temperature Data Retention (HTR) (SAR 45466).	2-3
	Updates made to maintain the style and consistency of the document.	NA
Revision 15 (July 2014)	Added corner pad table note (3) to "QN132 – Bottom View" (SAR 47442).	4-6
	Ambient temperature removed in Table 2-2, table notes and "ProASIC3 Ordering Information" figure were modified (SAR 48343).	2-2 1-IV
	Other updates were made to maintain the style and consistency of the datasheet.	NA
Revision 14 (April 2014)	Note added for the discontinuance of QN132 package to the following tables and section: "ProASIC3 Devices", "I/Os Per Package 1", "ProASIC3 FPGAs Package Sizes Dimensions" and "QN132 – Bottom View" section (SAR 55118).	I, III, 4-6



Revision	Changes	Page
v2.0 (continued)	Table 3-20 • Summary of I/O Timing Characteristics—Software Default Settings (Advanced) and Table 3-21 • Summary of I/O Timing Characteristics—Software Default Settings (Standard Plus) were updated.	3-20 to 3-20
	Table 3-11 • Different Components Contributing to Dynamic Power Consumption in ProASIC3 Devices was updated.	3-9
	Table 3-24 • I/O Output Buffer Maximum Resistances1 (Advanced) and Table 3-25 • I/O Output Buffer Maximum Resistances1 (Standard Plus) were updated.	3-22 to 3-22
	Table 3-17 • Summary of Maximum and Minimum DC Input Levels Applicable to Commercial and Industrial Conditions was updated.	3-18
	Table 3-28 • I/O Short Currents IOSH/IOSL (Advanced) and Table 3-29 • I/O Short Currents IOSH/IOSL (Standard Plus) were updated.	3-24 to 3-26
	The note in Table 3-32 • I/O Input Rise Time, Fall Time, and Related I/O Reliability was updated.	3-27
	Figure 3-33 • Write Access After Write onto Same Address, Figure 3-34 • Read Access After Write onto Same Address, and Figure 3-35 • Write Access After Read onto Same Address are new.	3-82 to 3-84
	Figure 3-43 • Timing Diagram was updated.	3-96
	Ambient was deleted from the "Speed Grade and Temperature Grade Matrix".	iv
	Notes were added to the package diagrams identifying if they were top or bottom view.	N/A
	The A3P030 "132-Pin QFN" table is new.	4-2
	The A3P060 "132-Pin QFN" table is new.	4-4
	The A3P125 "132-Pin QFN" table is new.	4-6
	The A3P250 "132-Pin QFN" table is new.	4-8
	The A3P030 "100-Pin VQFP" table is new.	4-11
Advance v0.7 (January 2007)	In the "I/Os Per Package" table, the I/O numbers were added for A3P060, A3P125, and A3P250. The A3P030-VQ100 I/O was changed from 79 to 77.	ii
Advance v0.6 (April 2006)	The term flow-through was changed to pass-through.	N/A
	Table 1 was updated to include the QN132.	ii
	The "I/Os Per Package" table was updated with the QN132. The footnotes were also updated. The A3P400-FG144 I/O count was updated.	ii
	"Automotive ProASIC3 Ordering Information" was updated with the QN132.	iii
	"Temperature Grade Offerings" was updated with the QN132.	iii
	B-LVDS and M-LDVS are new I/O standards added to the datasheet.	N/A
	The term flow-through was changed to pass-through.	N/A
	Figure 2-7 • Efficient Long-Line Resources was updated.	2-7
	The footnotes in Figure 2-15 • Clock Input Sources Including CLKBUF, CLKBUF_LVDS/LVPECL, and CLKINT were updated.	2-16
	The Delay Increments in the Programmable Delay Blocks specification in Figure 2-24 • ProASIC3E CCC Options.	2-24
	The "SRAM and FIFO" section was updated.	2-21



#### Datasheet Information

Revision	Changes	Page
Advance v0.3	The "PLL Macro" section was updated. EXTFB information was removed from this section.	2-15
	The CCC Output Peak-to-Peak Period Jitter F <sub>CCC_OUT</sub> was updated in Table 2-11 • ProASIC3 CCC/PLL Specification	2-29
	EXTFB was removed from Figure 2-27 • CCC/PLL Macro.	2-28
	Table 2-13 • ProASIC3 I/O Features was updated.	2-30
	The "Hot-Swap Support" section was updated.	2-33
	The "Cold-Sparing Support" section was updated.	2-34
	"Electrostatic Discharge (ESD) Protection" section was updated.	2-35
	The LVPECL specification in Table 2-43 • I/O Hot-Swap and 5 V Input Tolerance Capabilities in ProASIC3 Devices was updated.	2-64
	In the Bank 1 area of Figure 2-72, VMV2 was changed to VMV1 and VCCIB2 was changed to VCC $_{\rm I}$ B1.	2-97
	The VJTAG and I/O pin descriptions were updated in the "Pin Descriptions" section.	2-50
	The "JTAG Pins" section was updated.	2-51
	"128-Bit AES Decryption" section was updated to include M7 device information.	2-53
	Table 3-6 was updated.	3-6
	Table 3-7 was updated.	3-6
	In Table 3-11, PAC4 was updated.	3-93-8
	Table 3-20 was updated.	3-20
	The note in Table 3-32 was updated.	3-27
	All Timing Characteristics tables were updated from LVTTL to Register Delays	3-31 to 3- 73
	The Timing Characteristics for RAM4K9, RAM512X18, and FIFO were updated.	3-85 to 3-90
	F <sub>TCKMAX</sub> was updated in Table 3-110.	3-97
Advance v0.2	Figure 2-11 was updated.	2-9
	The "Clock Resources (VersaNets)" section was updated.	2-9
	The "VersaNet Global Networks and Spine Access" section was updated.	2-9
	The "PLL Macro" section was updated.	2-15
	Figure 2-27 was updated.	2-28
	Figure 2-20 was updated.	2-19
	Table 2-5 was updated.	2-25
	Table 2-6 was updated.	2-25
	The "FIFO Flag Usage Considerations" section was updated.	2-27
	Table 2-13 was updated.	2-30
	Figure 2-24 was updated.	2-31
	The "Cold-Sparing Support" section is new.	2-34

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